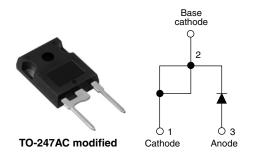


Vishay High Power Products

Input Rectifier Diode, 60 A



| PRODUCT SUMMARY | | |
|------------------------|--------|--|
| V _F at 60 A | 1.07 V | |
| I _{FSM} | 950 A | |
| V _{RRM} | 1600 V | |

DESCRIPTION/FEATURES

The 60EPS16PbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.



Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free.

| MAJOR RATINGS AND CHARACTERISTICS | | | | |
|-----------------------------------|------------------------------|-------------|-------|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | |
| I _{F(AV)} | Sinusoidal waveform | 60 | A | |
| V _{RRM} | | 1600 | V | |
| I _{FSM} | | 950 | A | |
| V _F | 60 A, T _J = 25 °C | 1.07 | V | |
| TJ | | - 40 to 150 | °C | |

| VOLTAGE RATINGS | | | | | |
|-----------------|---|--|----------------------------------|--|--|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA | | |
| 60EPS16PbF | 1600 | 1700 | 1 | | |

| ABSOLUTE MAXIMUM RATIN | GS | | | |
|--|--------------------|--|--------|--------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum average forward current | I _{F(AV)} | T_C = 118 °C, 180° conduction half sine wave | 60 | |
| Maximum peak one cycle non-repetitive surge current | 1 | 10 ms sine pulse, rated V_{RRM} applied | 950 | A |
| | I _{FSM} | 10 ms sine pulse, no voltage reapplied | 1100 | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V_{RRM} applied | 4512 | - A ² s |
| | 1-1 | 10 ms sine pulse, no voltage reapplied | 6300 | |
| Maximum I ² \sqrt{t} for fusing | l²√t | t = 0.1 to 10 ms, no voltage reapplied | 63 000 | A²√s |

* Pb containing terminations are not RoHS compliant, exemptions may apply

Vishay High Power Products Input Rectifier Diode, 60 A

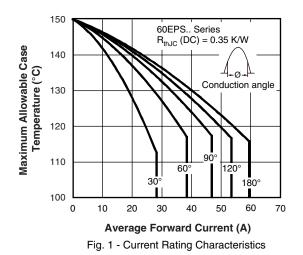


| ELECTRICAL SPECIFICATIONS | | | | | | |
|---------------------------------|-------------------------|------------------------------|-----------------------|--------|-------|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | |
| | M | 30 A, T _J = 25 °C | | 1.0 | V | |
| Maximum forward voltage drop | V _{FM} | 60 A, T _J = 25 °C | | 1.07 | v | |
| Forward slope resistance | ^r t T 150 °C | | 3.96 | mΩ | | |
| Threshold voltage | V _{F(TO)} | $T_J = 150 \text{ °C}$ | | 0.74 | V | |
| Maximum reverse leakage current | I _{RM} | T _J = 25 °C | V - Roted V | 0.1 | mA | |
| | | T _J = 150 °C | $V_R = Rated V_{RRM}$ | 1.0 | ША | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | |
|---|-----------------------------------|--------------------------------------|-------------|------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 40 to 150 | °C |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 0.35 | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | | 40 | °C/W |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased | 0.2 | |
| Approximate weight | | | 6 | g |
| | | | 0.21 | oz. |
| Mounting torque | | | 6.0 (5) | kgf ⋅ cm |
| Mounting torque maximum | | | 12 (10) | (lbf · in) |
| Marking device | | Case style TO-247AC modified (JEDEC) | 60EF | PS16 |



Input Rectifier Diode, 60 A Vishay High Power Products



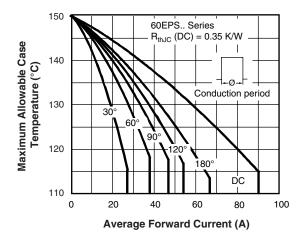
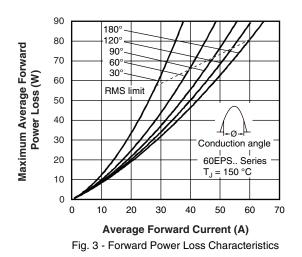


Fig. 2 - Current Rating Characteristics



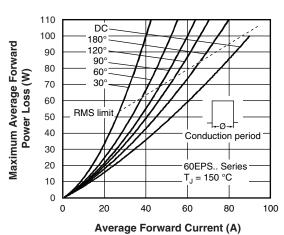


Fig. 4 - Forward Power Loss Characteristics

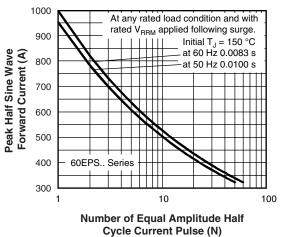
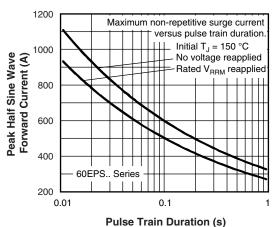


Fig. 5 - Maximum Non-Repetitive Surge Current





Vishay High Power Products Input Rectifier Diode, 60 A



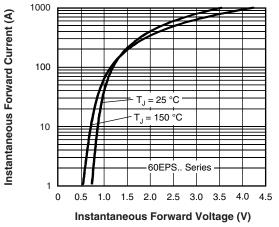


Fig. 7 - Forward Voltage Drop Characteristics

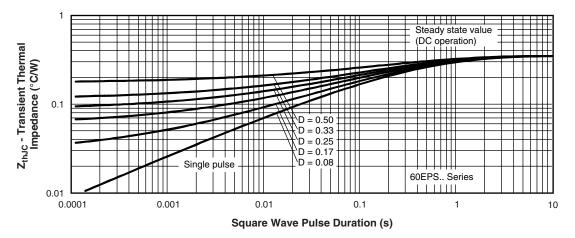
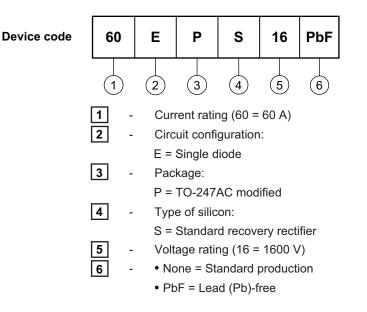


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Input Rectifier Diode, 60 A Vishay High Power Products

ORDERING INFORMATION TABLE



| LINKS TO RELATED DOCUMENTS | | | |
|--|---------------------------------|--|--|
| Dimensions http://www.vishay.com/doc?95253 | | | |
| Part marking information | http://www.vishay.com/doc?95255 | | |



Vishay

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